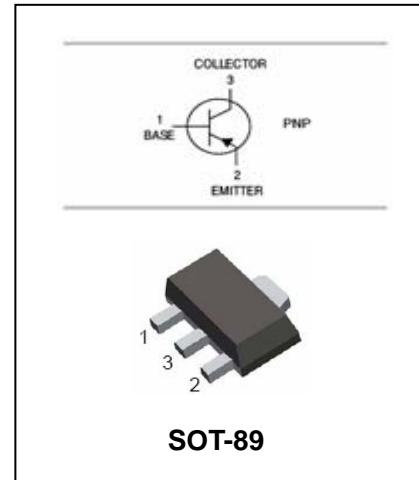


## PNP Silicon AF Transistors

## BCX69

### FEATURES

- For general AF applications.
- High collector current.
- High current gain.
- Low collector-emitter saturation voltage.
- Complementsry type:BCX68.



### ORDERING INFORMATION

Type No.	Marking	Package Code
BCX69	CE	SOT-89
BCX69-10	CF	SOT-89
BCX69-16	CG	SOT-89
BCX69-25	CH	SOT-89

### MAXIMUM RATING @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	-25	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-20	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current -Continuous	-1	A
I <sub>CM</sub>	Collector Current -Peak	-2	A
I <sub>B</sub>	Base Current	-0.1	A
I <sub>BM</sub>	Peak Base Current	-0.2	A
P <sub>D</sub>	Total Power Dissipation	1	W
T <sub>J</sub> , T <sub>stg</sub>	Junction and Storage Temperature	-65 to +150	°C



**PNP Silicon AF Transistors**

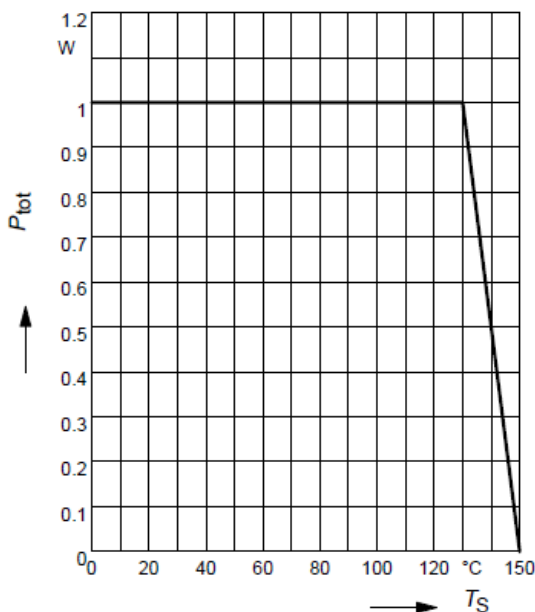
**BCX69**

**ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified**

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -10\mu A, I_E = 0$	-25		V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -30mA, I_B = 0$	-20		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -1\mu A, I_C = 0$	-5		$\mu V$
Collector cut-off current	$I_{CBO}$	$V_{CB} = -25V, I_E = 0$ $V_{CB} = -25V, I_E = 0, T_A = 150^\circ C$		-100 -100	nA $\mu A$
DC current gain	$h_{FE}$	$V_{CE} = -10V, I_C = -5mA$	50		
		$V_{CE} = -1V, I_C = -500mA$	85	375	
		BCX69-10	85	160	
		BCX69-16	100	250	
		$V_{CE} = -1V, I_C = -1A$	60		
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -1A, I_B = -100mA$		-0.5	V
Base-emitter voltage	$V_{BE}$	$I_C = -1A, V_{CE} = -1V$		-1	V
Transition frequency	$f_T$	$V_{CE} = -5V, I_C = -100mA,$ $f = 20MHz$	100		MHz

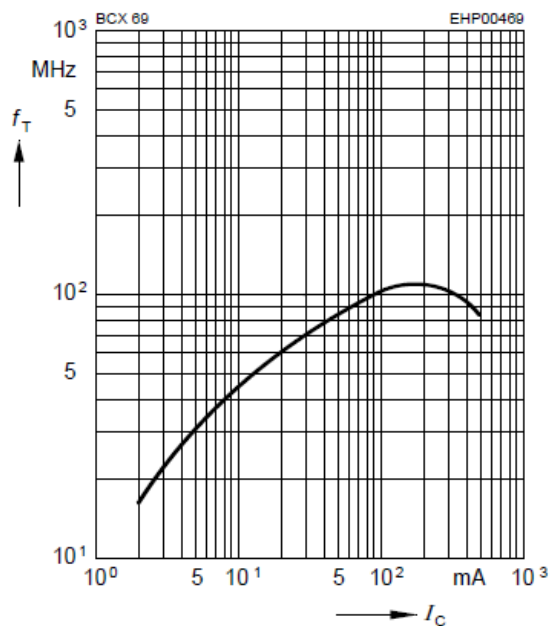
**TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified**

**Total power dissipation  $P_{tot} = f(T_S)$**



**Transition frequency  $f_T = f(I_C)$**

$V_{CE} = 5V$

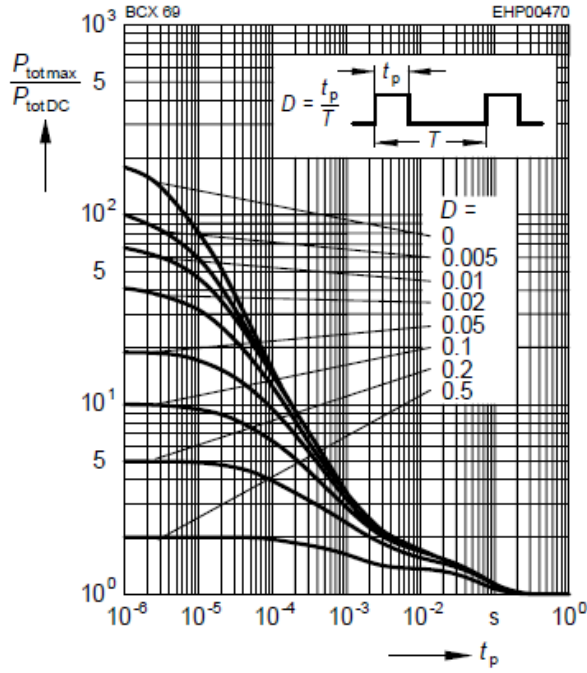


**PNP Silicon AF Transistors**

**BCX69**

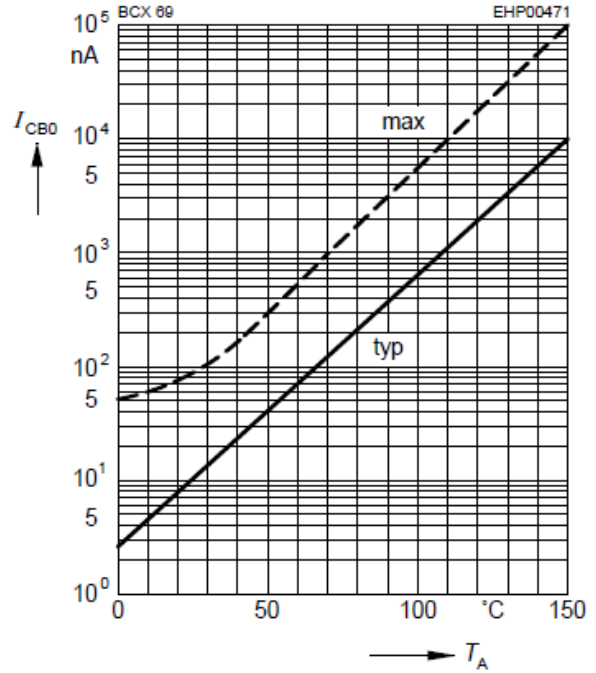
**Permissible pulse load**

$$P_{totmax} / P_{totDC} = f(t_p)$$



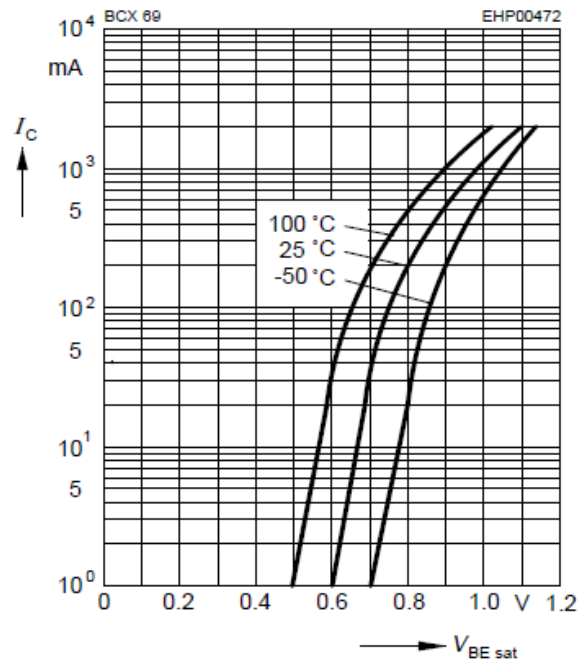
**Collector cutoff current  $I_{CBO} = f(T_A)$**

$$V_{CB} = 25V$$



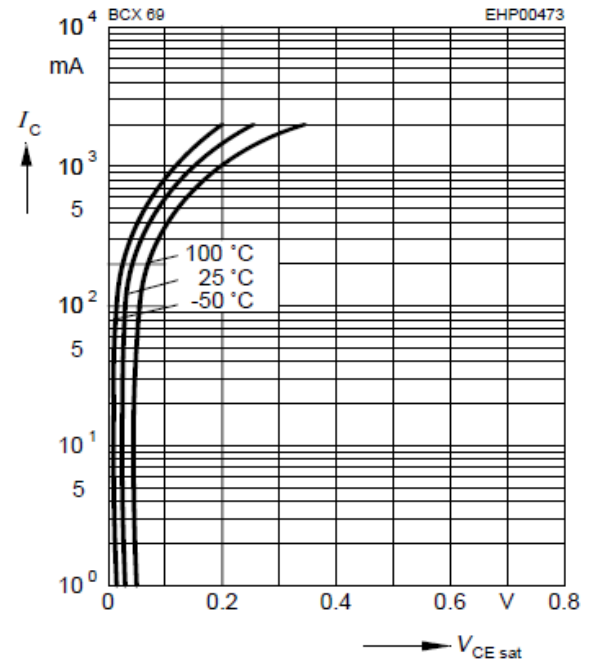
**Base-emitter saturation voltage**

$$I_C = f(V_{BEsat}), h_{FE} = 10$$



**Collector-emitter saturation voltage**

$$I_C = f(V_{CEsat}), h_{FE} = 10$$





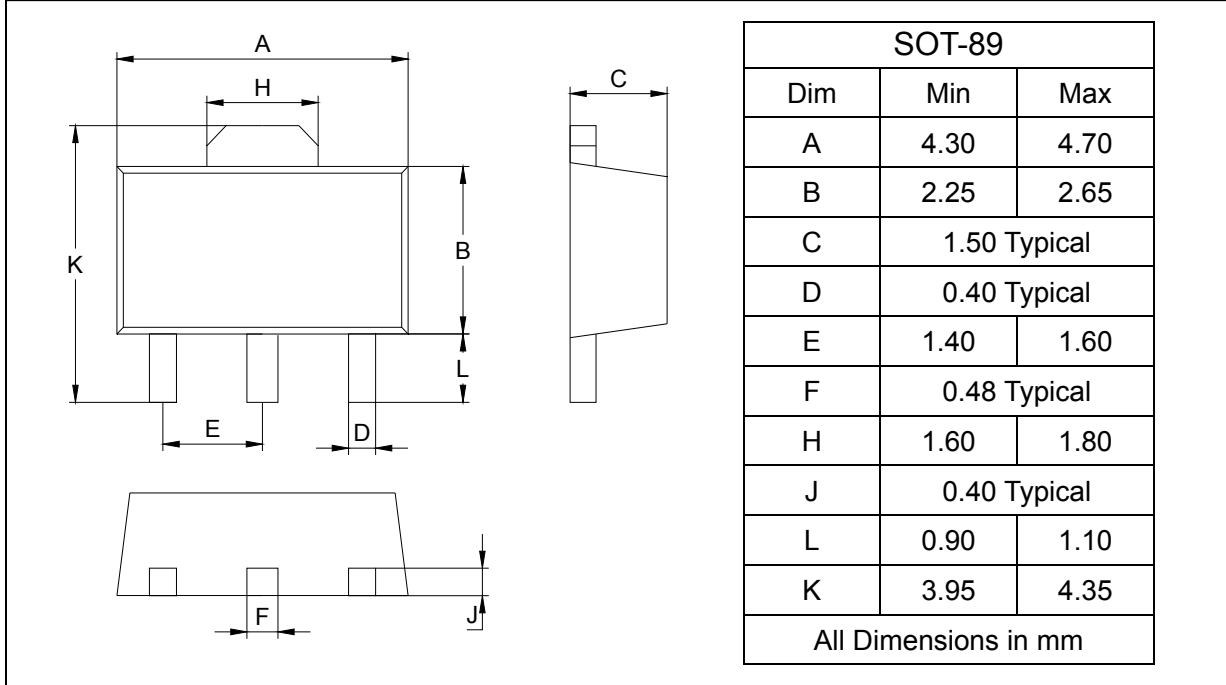
**PNP Silicon AF Transistors**

**BCX69**

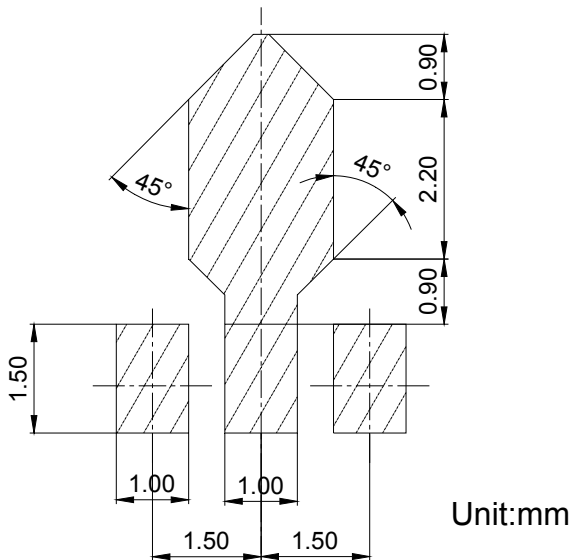
**PACKAGE OUTLINE**

Plastic surface mounted package

SOT-89



**SOLDERING FOOTPRINT**



**PACKAGE INFORMATION**

Device	Package	Shipping
BCX69	SOT-89	1000/Tape&Reel